## MN39160FH

## 4.5 mm (type-1/4) 680k-pixel CCD Area Image Sensor

## Overview

The MN39160FH is a 4.5 mm (type-1/4) interline transfer CCD (IT-CCD) solid state image sensor device.

This device uses photodiodes in the optoelectric conversion section and CCDs for signal readout. The electronic shutter function has made an exposure time of $1 / 10000$ seconds possible. Further, this device has the features of high sensitivity, low noise, broad dynamic range, and low smear.

This device has a total of 681739 pixels ( 1007 horizontal $\times 677$ vertical) and provides stable and clear images with a resolution of 600 horizontal TV-lines and 420 vertical TV-lines.

| Part Number | Size | System | Color or B/W |
| :---: | :---: | :---: | :---: |
| MN39160FH | $4.5 \mathrm{~mm}(\mathrm{type}-1 / 4)$ | NTSC | Color |

## Features

- Effective pixel number 962 (horizontal) $\times 654$ (vertical)
- High sensitivity
- Broad dynamic range
- Low smear
- Electronic shutter


## Applications

- Camcorders
- FA, OA cameras

■ Pin Assignments


## Block Diagram


*1: TEST pin must be left open, because the pin outputs CCD internal bias voltage.

- Pin Descriptions

| Pin No. | Symbol | Description | Pin No. | Symbol | Description |
| :---: | :---: | :--- | :---: | :---: | :--- |
| 1 | $\phi_{\mathrm{V} 4}$ | Vertical shift register clock pulse 4 | 8 | VO | Video output |
| 2 | $\phi_{\mathrm{V} 3}$ | Vertical shift register clock pulse 3 | 9 | GND | GND |
| 3 | $\phi_{\mathrm{V} 2}$ | Vertical shift register clock pulse 2 | 10 | $\phi_{\mathrm{R}}$ | Reset pulse (RG) |
| 4 | $\phi_{\mathrm{V} 1}$ | Vertical shift register clock pulse 1 | 11 | $\phi_{\mathrm{H} 1}$ | Horizontal register clock pulse 1 |
| 5 | GND | GND | 12 | $\phi_{\mathrm{H} 2}$ | Horizontal register clock pulse 2 |
| 6 | TEST | TEST pin (OPEN) ${ }^{* 1}$ | 13 | Sub | Substrate |
| 7 | $\mathrm{~V}_{\mathrm{DD}}$ | Power supply | 14 | PT | P-well for protection circuit |

Note) $* 1$ : TEST pin must be left open, because the pin outputs CCD internal bias volltage.

## Device Parameter $(\mathrm{H} \times \mathrm{V})$

| Parameter | Value | Unit |
| :--- | :---: | :---: |
| Pixel number ${ }^{* 1}$ | $962 \times 654$ | pixel |
| Image sensing block dimension | $3.6556 \times 2.7141$ | $\mathrm{~mm}^{2}$ |
| Pixel dimension | $3.80 \times 4.15$ | $\mu \mathrm{~m}^{2}$ |

Note) $* 1: \mathrm{OB}$ columns are not included.

Absolute Maximum Ratings and Operating Conditions

| Parameter |  | Absolute maximum rating |  | Operating condition |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Lower limit | Upper limit | Min | Typ | Max |  |
| $\mathrm{V}_{\mathrm{DD}}$ |  | -0.2 | 18 | 14.5 | 15.0 | 15.5 | V |
| $\mathrm{V}_{\mathrm{PT}}{ }^{* 3,4}$ |  | -10.0 | 0.2 | -7.5 | -7.0 | -6.5 | V |
| GND |  | (Reference voltage) |  | - | 0 | - | V |
| $\mathrm{V}_{\text {¢R }}$ | High-Low | - | 8 | 3.0 | 3.3 | 3.6 | V |
|  | Bias | (Supplied internally) |  |  |  |  | V |
| $\mathrm{V}_{\mathrm{\phi H} 1}$ | High | - | 8 | 3.0 | 3.3 | 3.6 | V |
|  | Low | -0.2 | - | -0.2 | 0 | 0.2 | V |
| $\mathrm{V}_{\mathrm{\phi H} 2}$ | High | - | 8 | 3.0 | 3.3 | 3.6 | V |
|  | Low | -0.2 | - | -0.2 | 0 | 0.2 | V |
| $\mathrm{V}_{\text {Sub }} * 2$ |  | (Supplied internally) |  |  |  |  | V |
| $\phi V_{\text {Sub }}{ }^{* 1}$ |  | $-0.2$ | 35 | 21.0 | 22.0 | 23.0 | V |
| $\mathrm{V}_{\mathrm{\phi V} 1} * 3,4$ | High | - | 18 | 14.5 | 15.0 | 15.5 | V |
|  | Middle | - | - | $-0.05$ | 0 | 0.05 | V |
|  | Low | -9 | - | -7.5 | -7.0 | -6.5 | V |
| $\mathrm{V}_{\mathrm{\phi V} 2} * 3,4$ | Middle | - | 15 | $-0.05$ | 0 | 0.05 | V |
|  | Low | -9 | - | -7.5 | -7.0 | -6.5 | V |
| $\mathrm{V}_{\mathrm{\phi V} 3} * 3,4$ | High | - | 18 | 14.5 | 15.0 | 15.5 | V |
|  | Middle | - | - | -0.05 | 0 | 0.05 | V |
|  | Low | -9 | - | -7.5 | -7.0 | -6.5 | V |
| $\mathrm{V}_{\phi \mathrm{V} 4} * 3,4$ | Middle | - | 15 | -0.05 | 0 | 0.05 | V |
|  | Low | -9 | - | -7.5 | -7.0 | -6.5 | V |
| Operating temperature |  | -10 | 60 | - | 25 | - | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature |  | -30 | 80 | - | - | - | ${ }^{\circ} \mathrm{C}$ |

## Absolute Maximum Ratings and Operating Conditions (continued)

Note) 1. Standard photo detecting condition
Standard photo detecting condition stands for detecting image with a light source of color temperature of 2856 K , luminance of $1050 \mathrm{~cd} / \mathrm{m}^{2}$, and using a color temperature conversion filter LB-40 (HOYA), infrared cut filter CAW-500S with thickness 2.5 mm for a light path and with F8 lens aperture. The quantity of the incidental light to a photo-detecting surface under the above condition is defined as the standard quantity of light.
2. $* 1: \mathrm{V}_{\text {Sub }}$ when using electronic shutter function

*2: $\mathrm{V}_{\text {Sub }}$ supplied internally is the voltage suppressing the blooming generation at $\times 500$ light quantity relative to the standard light quantity.
*3: Relation between $\mathrm{V}_{\mathrm{PT}}$ and $\mathrm{V}_{\phi \mathrm{VL}}$
Set $\mathrm{V}_{\mathrm{PT}}$ under the following condition against VL of a vertical transfer clock waveform.

$$
\mathrm{V}_{\mathrm{PT}} \leq \mathrm{VL}\left(\mathrm{~V}_{\phi \mathrm{V} 1 \mathrm{~L}} \text { to } \mathrm{V}_{\phi \mathrm{V} 4 \mathrm{~L}}\right)
$$

*4: Absolute maximum ratings $\quad-0.2<\mathrm{V}_{\phi \mathrm{V}}-\mathrm{V}_{\mathrm{PT}}<24.5(\mathrm{~V})$

## Optical Characteristics

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: |
| Carrier saturation output | Sc | J chart | 500 | - | - | mV |
| Sensitivity | So | J chart F1.4, 1/32 ND | 80 | 110 | - | mV |
| Vertical smear | Sm | $1 / 10$ V chart, F1.4 | - | - | 0.01 | $\%$ |

Note) The above-mentioned characteristics are the values on driving the device for the imaging stabilizer mode (1/60 seconds accumulation).

Timing Diagram

- High speed pulse timing


Timing Diagram (continued)

- Rise time and fall time of each pulse
$\phi_{\mathrm{V} 1}, \phi_{\mathrm{V} 3}$

$\phi_{\mathrm{V} 2}, \phi_{\mathrm{V} 4}$

$\phi_{\mathrm{H} 1}, \phi_{\mathrm{H} 2}$

$\phi_{R}$


Color Filter Arrays on CCD


## Graph of Characteristics

CCD color filter spectral characteristics


Package Dimensions (unit: mm)

- WDIP014-P-0400H


1. The center of the package is equal to the center of the effective pixel area.
2. The rotation angle of the effective pixel area: up to $\pm 1.0$ degree
3. The distance from the bottom face of the package to the surface of the effective pixel area: $1.41 \mathrm{~mm} \pm 0.1 \mathrm{~mm}$
4. The tilt of the effective pixel area for the bottom face of the package: up to $25 \mu \mathrm{~m}$
5. Thickness of seal glass is $0.7 \mathrm{~mm} \pm 0.1 \mathrm{~mm}$, and the refractive index is 1.50 .
6. Package weight: 0.55 g (typ.)

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